



PB-03M Specification

Version V1.0.0

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1. Product Overview

PB-03M is a BLE module developed by Shenzhen Ai-Thinker Technology Co., Ltd. The core processor chip PHY6252(SSOP24) of this module is a BLE SoC with high integration and low power consumption, which is specially designed for various applications such as IoT, mobile devices, wearable electronic devices and smart homes.

PHY6252(SSOP24) chip has industry-leading low power consumption performance and RF performance, it supports BLE 5.2. The chip built in 64 KB SRAM, 256KB flash, 96 KB ROM, 256bit efuse. The chip supports a variety of low-power working states and can meet the power consumption requirements of various application scenarios. RF output power can be adjusted to achieve the best balance among communication distance, communication rate and power consumption.

PB-03M module provide rich peripheral interfaces, including UART, PWM, ADC, I2C, SPI, PDM, DMA and up to 15 IOs.

PB-03M module has many unique hardware security mechanisms. Hardware encryption accelerator supports AES algorithm.

PB-03M module supports BLE with low power consumption: BLE 5.2 and BLE mesh. Bluetooth rate support: 125Kbps, 500Kbps, 1Mbps, 2Mbps. Support broadcast expansion, multi-broadcast, channel selection.

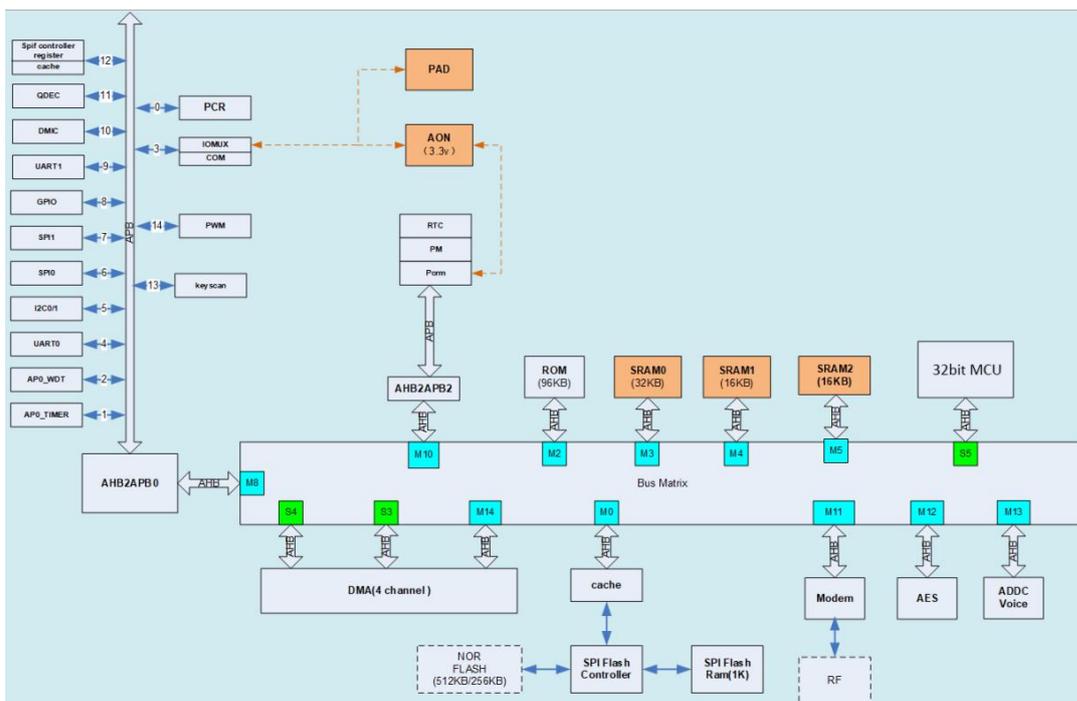


Figure 1 Main chip architecture diagram

1.1. Characteristic

- Support BLE5.2, rate support:125Kbps, 500Kbps, 1Mbps, 2Mbps
- Own 64 KB SRAM, 256KB flash, 96 KB ROM, 256bit efuse
- Support UART/GPIO/ADC/PWM/I2C/SPI/PDM/DMA interface
- Adopt DIP-18 Gold finger plugin package
- Support multiple sleep modes, deep sleep current is less than 1uA
- Support for serial local upgrade and remote Firmware upgrade (FOTA)
- Universal AT instructions can be used easy and quickly
- Support for secondary development, with an integrated Windows development environment

2. Main parameters

Table 1 Description of the main parameters

Model	PB-03M
Package	DIP-18 Gold finger plugin
Size	18.0*18.0*2.8(±0.2)mm
Antenna	On-board antenna
Frequency	2400 ~ 2483.5MHz
Operating temperature	-40 °C ~ 85 °C
Storage temperature	-40 °C ~ 125 °C , < 90%RH
Power supply	Voltage 2.7V ~ 3.6V, Current >200mA
Interface	UART/GPIO/ADC/PWM/I2C/I2S/SPI/PDM/DMA
IO	15
UART rate	Default 115200 bps
Bluetooth	BLE 5.2
Security	AES-128
SPI Flash	256KB

2.1. Static electricity requirements

PB-03M is an electrostatic sensitive device, and special precautions must be taken when handling it.



Figure 2 ESD anti-static diagram

2.2. Electrical characteristics

Table 2 Electrical characteristics table

Parameters		Conditions	Min.	Typical value	Max.	Unit
Power supply voltage		VDD	2.7	3.3	3.6	V
I/O	V_{IL}/V_{IH}	-	-0.3/0.75V DD	-	0.25VDD/VDD +0.3	V
	V_{OL}/V_{OH}	-	N/0.8VIO	-	0.1VIO/N	V
	I_{MAX}	-	-	-	12	mA

2.3. BLE RF performance

Table 3 BLE RF performance table

Description	Typical values			Unit
Operating frequency	2400 - 2483.5			MHz
Output power				
Mode	Min.	typical value	Max.	Unit
BLE 2Mbps	-20	8	10	dBm
BLE 1Mbps	-20	8	10	dBm
BLE 500Kbps	-20	8	10	dBm
BLE 125kbps	-20	8	10	dBm
Receiving sensitivity				
Mode	Min.	typical value	Max.	Unit

BLE 2Mbps	-	-93	-	dBm
BLE 1Mbps	-	-96	-	dBm
BLE 500Kbps	-	-97	-	dBm
BLE 125Kbps	-	-102	-	dBm

2.4. Power consumption

The following power consumption data are based on a 3.3V power supply, ambient temperature of 25°C and measured using an internal regulator.

- All measurements were completed without the SAW filter at the antenna interface.
- All emission data were measured based on the TX_Burst_Test & RX_Burst_Test mode

Table 4 Power consumption table

Mode	Min.	Average value	Max.	Unit
TX_Burst_Test Power output 8dBm	-	11.5	-	mA
TX_Burst_Test Power output 5dBm	-	9	-	mA
TX_Burst_Test Power output 0dBm	-	8	-	mA
RX_Burst_Test	-	9.4	-	mA
Deep Sleep(With broadcast, 1 second interval)	-	50.58	-	uA
Deep Sleep(With broadcast, 2 seconds interval)	-	28.25	-	uA
Deep Sleep(Without broadcast)	-	7.2	-	uA
Power Off	-	0.57	-	uA

3. Appearance dimensions

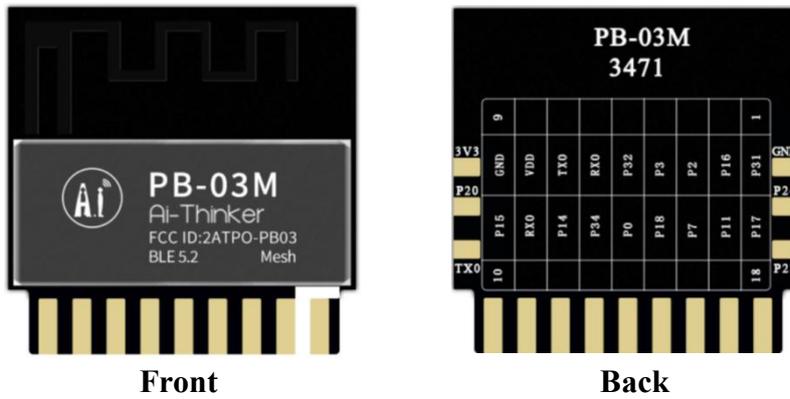


Figure 3 Appearance diagram pictures is for reference only, subject to physical objects)

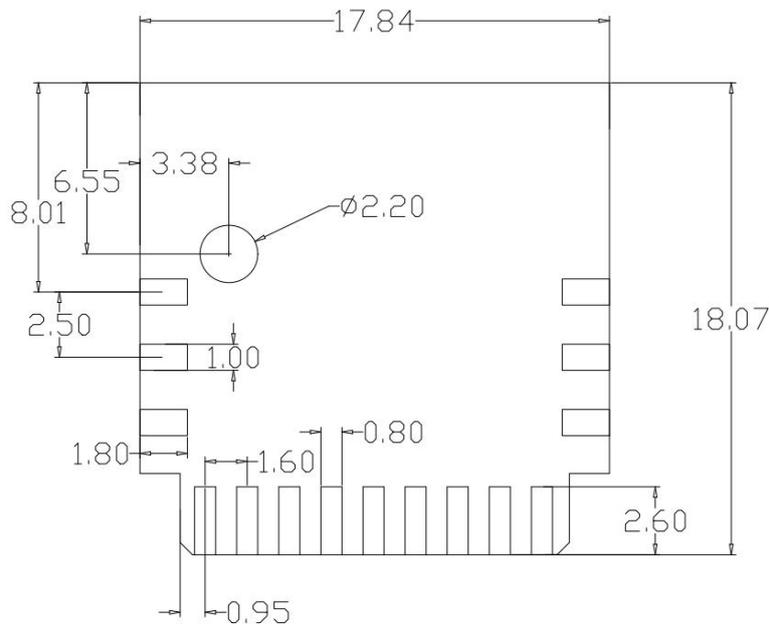


Figure 4 Module size diagram

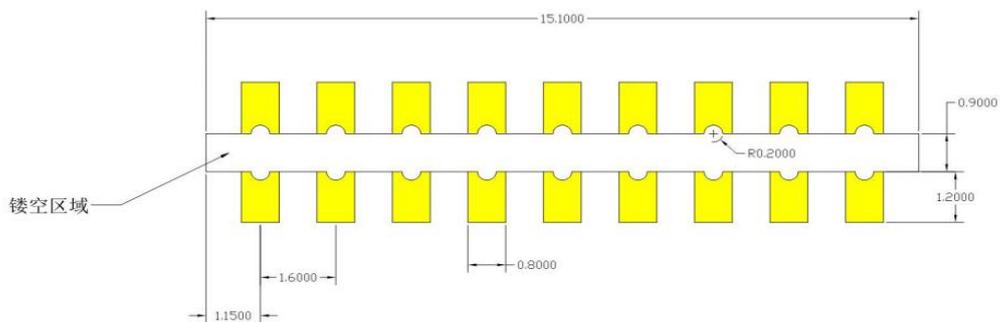


Figure 5 Recommended package of the plug-in

Table 6 Pin function definition table

No.	Name	Function
1	P31	GPIO31
2	P16	GPIO16/32.768KHz crystal input
3	P2	GPIO2/SWD debug data inout
4	P3	GPIO3/SWD debug clock
5	P32	GPIO32
6	P10	RXD/GPIO10
7	P9	TXD/GPIO9
8	VDD	Power input
9	GND	Ground (Power negative electrode)
10	P15	GPIO15/ADC input 4/micbias output
11	P10	GPIO10/RXD
12	P14	GPIO14/ADC input 3
13	P34	GPIO34
14	P0	GPIO0
15	P18	GPIO18/ADC input 7/PGA negative input
16	P7	GPIO7
17	P11	GPIO11/ADC input 0
18	P17	GPIO17/32.768KHz crystal output

5. Schematic

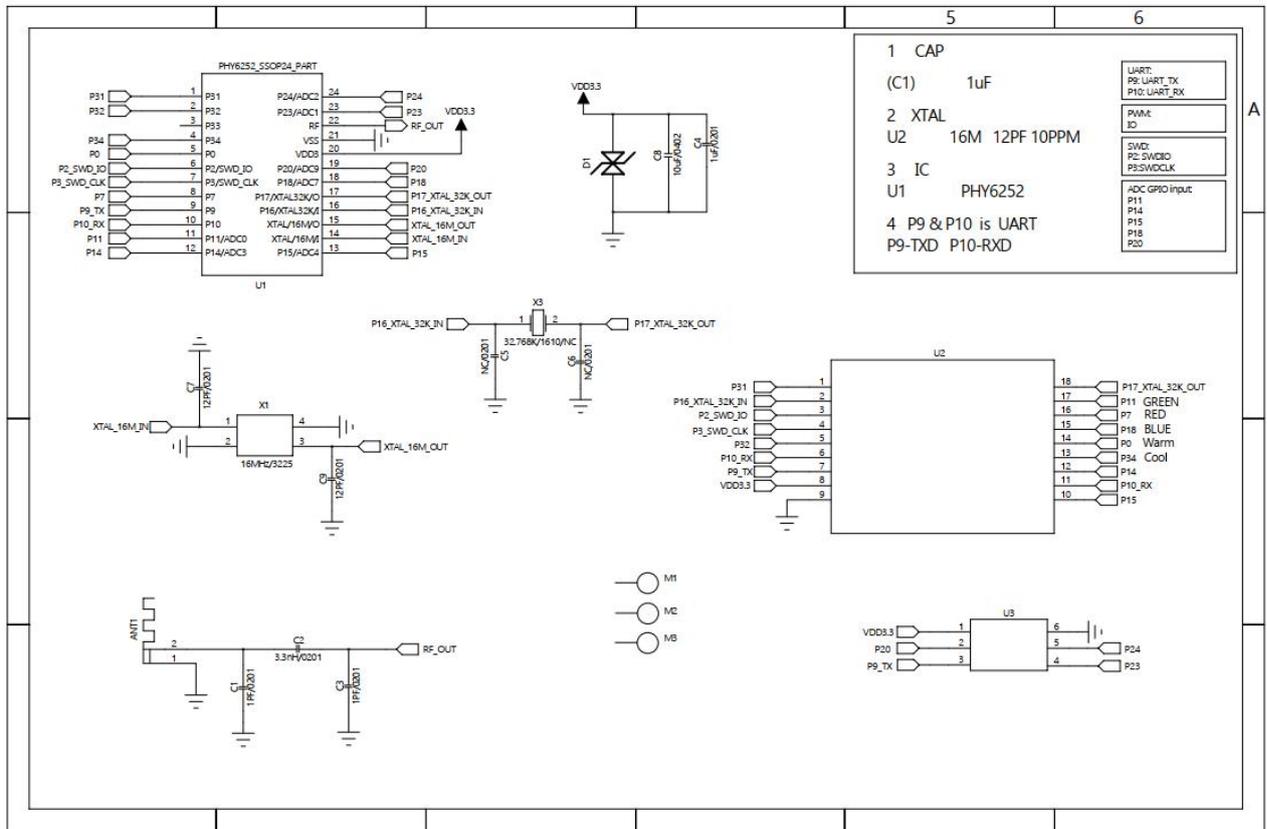


Figure 7 Module schematic

6. Antenna parameters

6.1. Test conditions for the antenna



Figure 8 Antenna test conditions

6.2. Antenna S parameter

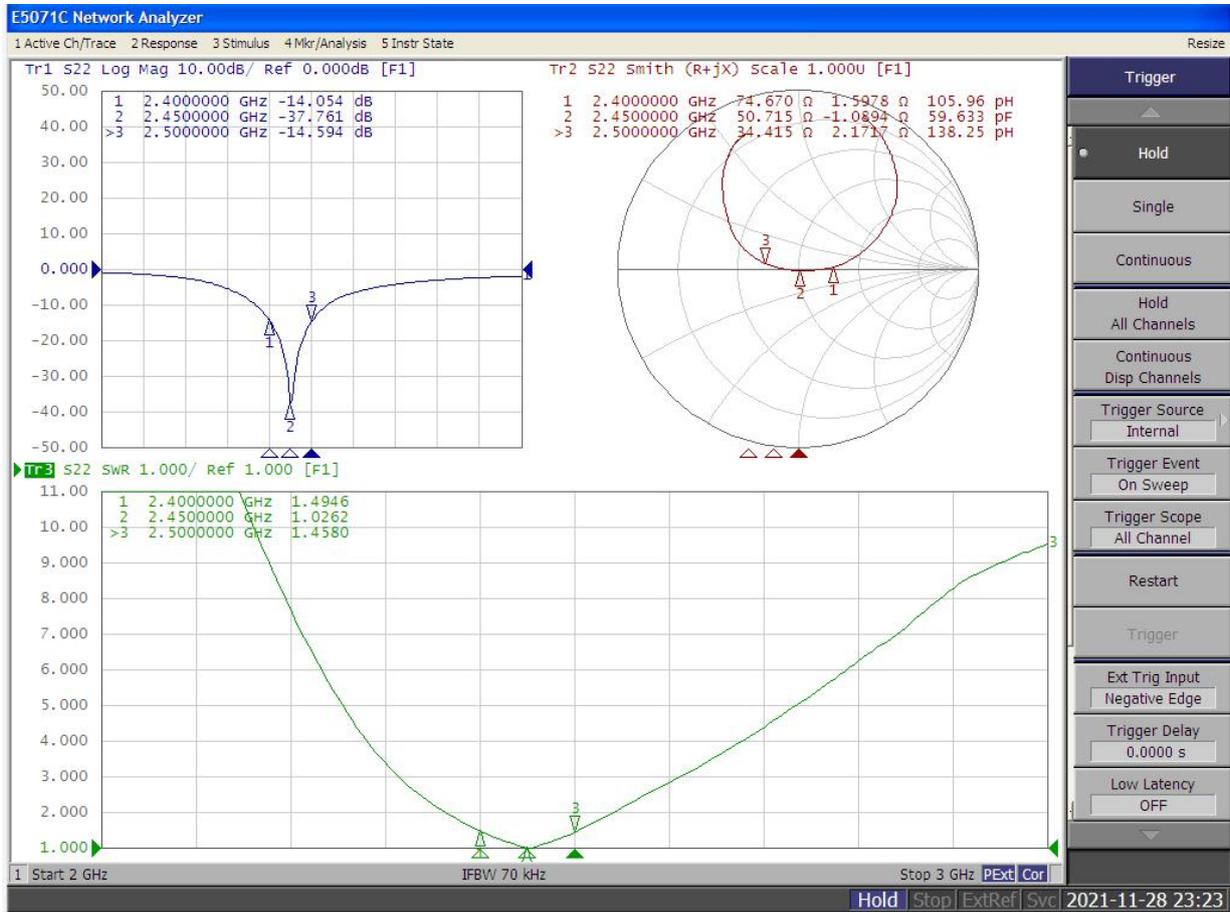


Figure 9 Antenna S parameters

6.3. Antenna Gain and Efficiency

Table 7 Antenna Gain and efficiency

Frequency ID	1	2	3	4	5	6	7	8	9	10	11
Frequency (MHz)	2400.0	2410.0	2420.0	2430.0	2440.0	2450.0	2460.0	2470.0	2480.0	2490.0	2500.0
Gain (dBi)	0.98	1.09	1.05	0.95	0.94	1.11	1.39	1.65	1.72	1.86	1.76
Efficiency (%)	49.69	51.06	51.50	51.96	52.35	53.98	55.58	56.94	57.07	59.47	58.11

6.4. Antenna field type diagram

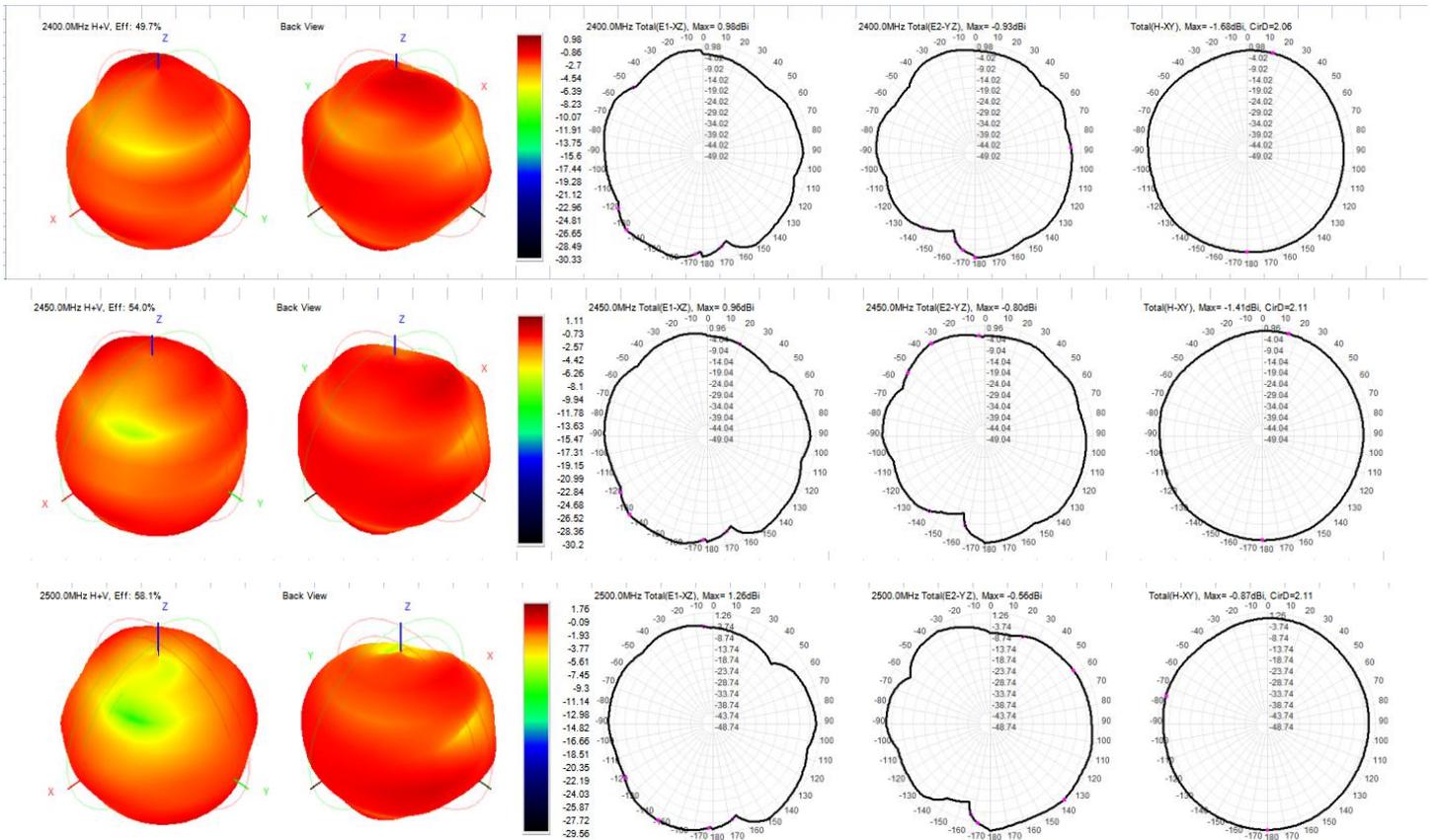


Figure 10 Antenna field type diagram

7. Design guidance

7.1. Module application circuit

($\geq 200\text{mA}$, suggest use DC-DC or LDO independent power supply)

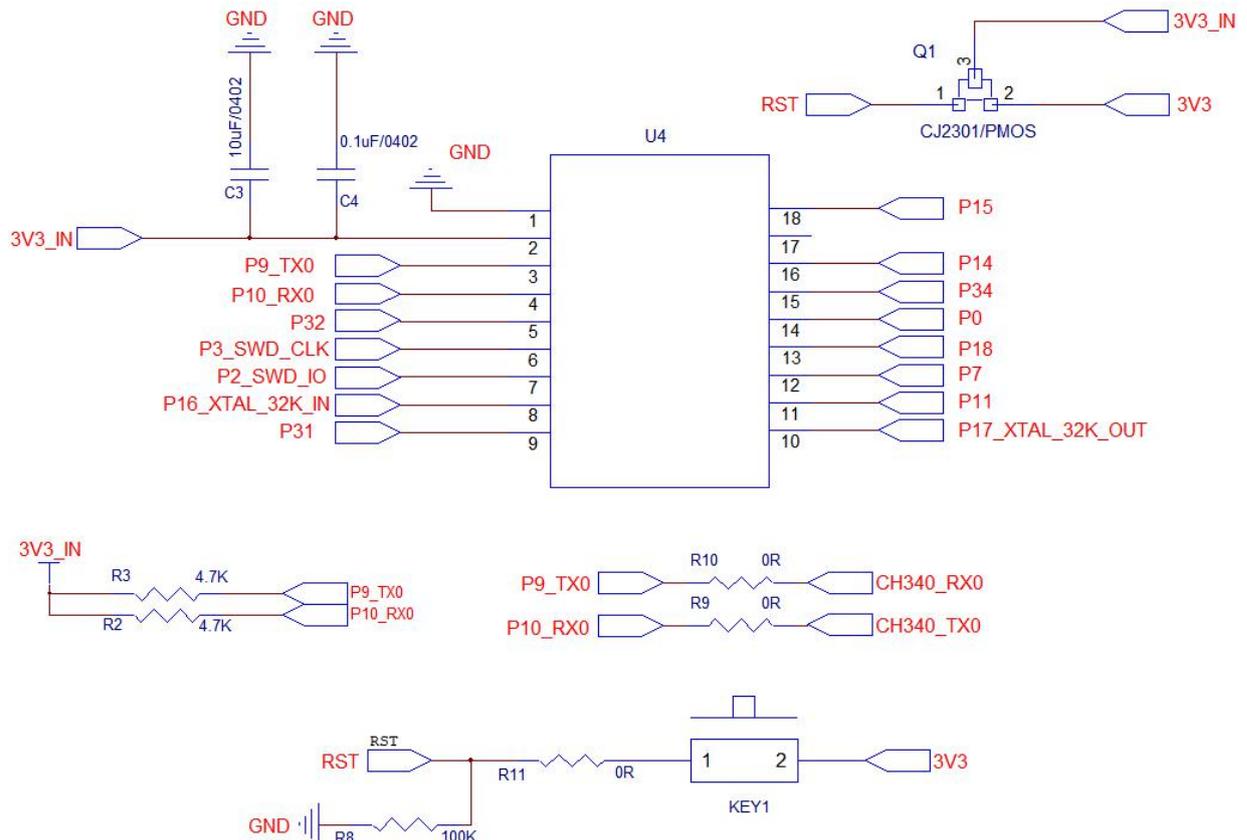


Figure 11 Application circuit diagram

Note:

- Because the PB-03M does not have the reset pin, we can achieve the reduction by power off, we can restore the module with a PMOS to achieve the reduction of power off.
- TX & RX serial port line, 2 resistors are reserved, in series in the line. The 3.3V voltage used to prevent the serial port affects the reset of the module.

7.2. Antenna layout requirements

- The installation position on the motherboard suggests the following 2 ways:

Scheme 1: Put the module on the edge of the motherboard, and the antenna area out of the motherboard edge

Scheme 2: Put the module on the edge of the motherboard, and empty an area along the antenna position.

- To meet the performance of the on-board antenna, metal parts are not placed around the antenna, away from the high-frequency device

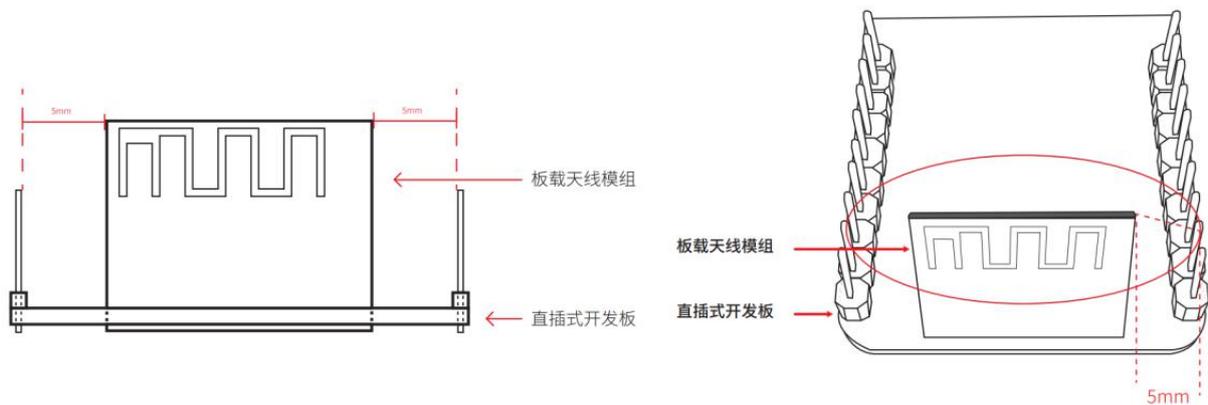


Figure 12 Schematic diagram of the antenna layout

7.3. Power supply

- Recommended 3.3V voltage, peak current over 200mA.
- Power supply is recommend to use LDO ; If the DC-DC is used, the ripple is recommended to be controlled within 30mV
- The DC-DC power supply circuit proposes to reserve the dynamic response capacitance to optimize the output ripple with large load changes.
- 3.3V power interface it is recommended to add ESD devices.

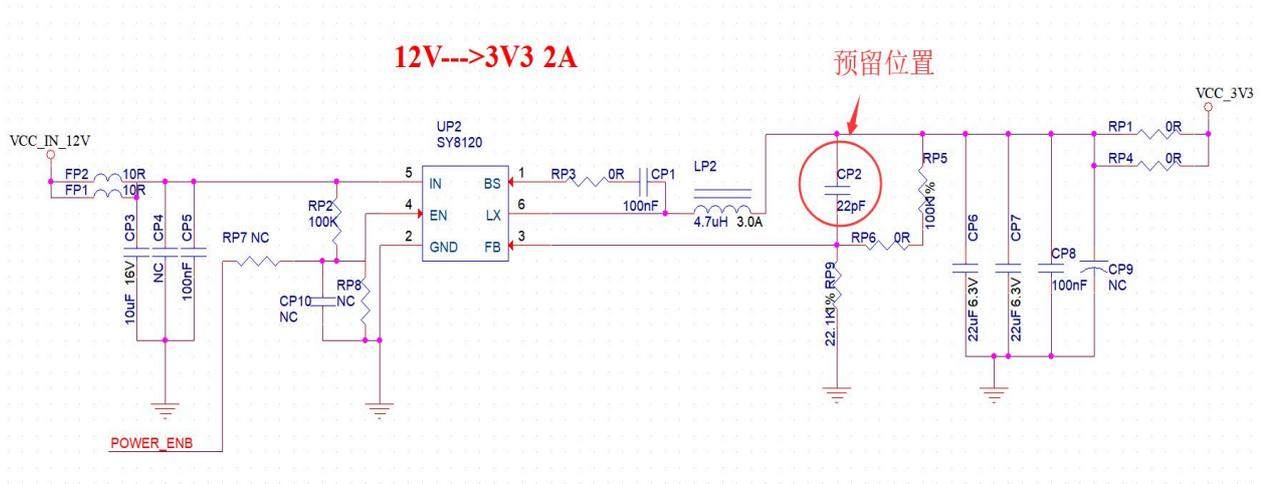


Figure 13 The DC-D C antihypertensive circuit diagram

7.4. GPIO

- Some IO ports are lead outside the module, if using, a proposed resistance of 10-100 ohms on the IO port. This suppresses the overshoot and enables smoother levels on both sides, helping for both EMI and ESD.
- The up and down of the special IO port should refer to the use instructions of the specification, which will affect the start-up configuration of the module.
- The IO port of the module is 3.3V, if the main control does not match the IO port level of the module, the level conversion circuit should be increased.
- If the IO port is directly connected to the peripheral interface, or terminals such as pin header, it is recommended to reserve ESD devices at the IO port line near the terminal.

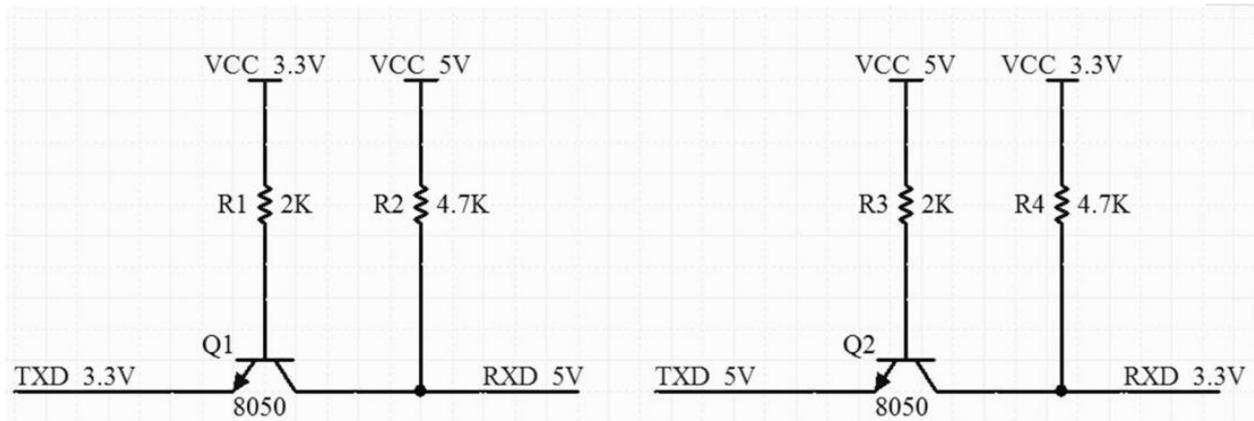


Figure 14 Level convert circuit

8. Flow welding curve diagram

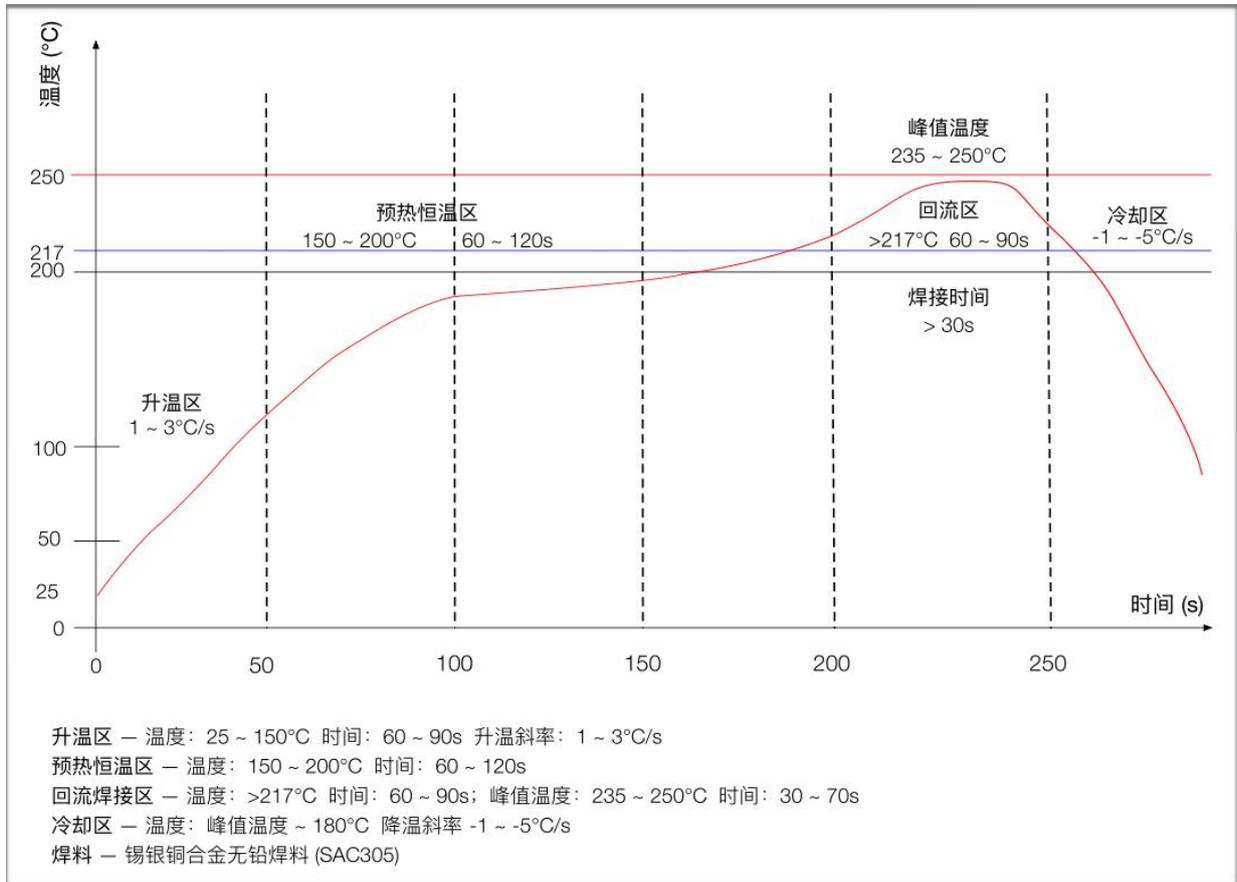


Figure 15 Flow welding diagram

9. Product related models

Table 8 Product related model list

Model	Power Supply	Package	Size	Antenna
PB-03F	2.7V ~ 3.6V, I>200mA	SMD-22	24.0*16.0*3.1(± 0.2)mm	On-board PCB
PB-03M	2.7V ~ 3.6V, I>200mA	DIP-18 Gold finger plugin	18.0*18.0*2.8(± 0.2)mm	On-board PCB
PB-03	2.7V ~ 3.6V, I>200mA	SMD-61	16.6*13.2*2.8(± 0.2)mm	On-board PCB
NodeMCU- PB-03F-Kit	5V, I>200mA	DIP-30	49.3*25.4*12.9(±0.2)mm	On-board PCB
NodeMCU- PB-03M-Kit	5V, I>200mA	DIP-20	32.8*28.6*18.3(±0.2)mm	On-board PCB
NodeMCU- PB-03-Kit	5V, I>200mA	DIP-30	49.3*25.4*12.9(±0.2)mm	On-board PCB
Product related information: https://docs.ai-thinker.com				

10. Product packaging information

PB-03M module was packaged in a tape, 800pcs/reel. As shown in the below image:



Figure 16 Package and packing diagram

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[Taobao shop](#)

[Alibaba shop](#)

[Technic support email: support@aithinker.com](mailto:support@aithinker.com)

[Domestic business cooperation: sales@aithinker.com](mailto:sales@aithinker.com)

[Overseas business cooperation: overseas@aithinker.com](mailto:overseas@aithinker.com)

Company Address: Room 403,408-410, Block C, Huafeng Smart Innovation Port, Gushu 2nd Road, Xixiang, Baoan District, Shenzhen.

Tel: +86-0755-29162996



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